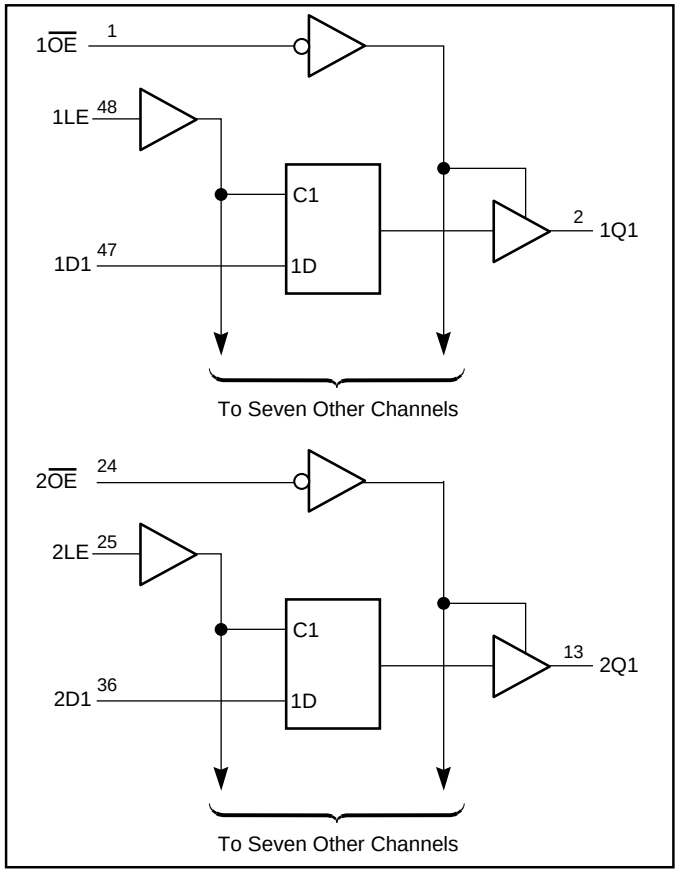
PI74VCX16373

16-Bit Transparent D-Type Latch with 3-State Outputs

Product Features

- The PI74VCX Family is designed for low voltage operation, V_{DD} = 1.8V to 3.6V
- 3.6V I/O Tolerant Inputs and Outputs
- Supports Live Insertion
- Balanced Drive, ±24mA
- Uses patented Noise Reduction Circuitry
- Typical V_{OLP} (Output Ground Bounce) < 0.6V at V_{DD} = 2.5V, T_A = 25ºC
- Typical V_{OHV} (Output V_{OH} Undershoot) < -0.6V at V_{DD} = 2.5V, T_A = 25ºC
- Power-Off high impedance inputs and outputs
- Industrial operation at –40°C to +85°C
- Packages available:
  – 48-pin 240 mil. wide plastic TSSOP (A)
  – 48-pin 300 mil. wide plastic SSOP (V)

Logic Block Diagram



Product Description

Pericom Semiconductor's PI74VCX series of logic circuits are produced in the Company's advanced 0.35 micron CMOS technology, achieving industry leading speed.

The PI74VCX16373 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. This device can be used as two 8-bit latches or one 16-bit latch. When the Latch Enable (LE) input is HIGH, the Q outputs follow the (D) inputs. When LE is taken LOW, the Q outputs are latched at the levels set up at the D inputs.

A buffered Output Enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state in which the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components. $\overline{OE}$ does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high impedance state.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The PI74VCX family is I/O Tolerant, allowing it to operate in mixed 1.8V/3.6V systems.

Product Pin Description

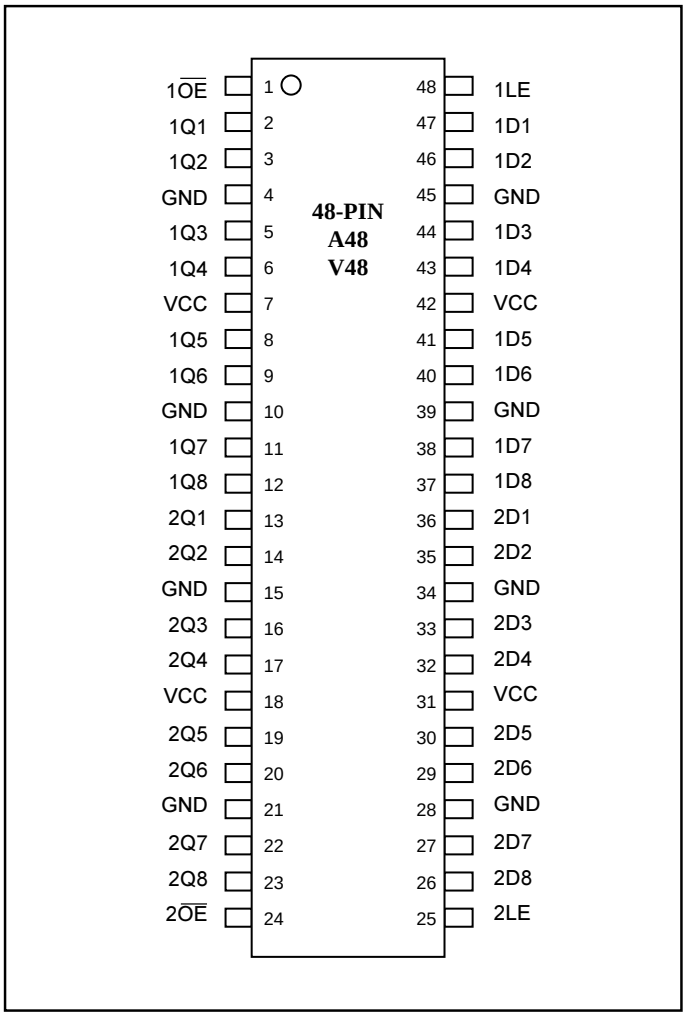
Pin Name	Description
$\overline{OE}$	Output Enable Input (Active LOW)
LE	Latch Enable (Active HIGH)
Dx	Data Inputs
Qx	3-State Outputs
GND	Ground
VCC	Power

Truth Table(1)

Inputs			Outputs
$\overline{OE}$	LE	D	Q
L	H	H	H
L	H	L	L
L	L	X	Q0
H	X	X	Z

Notes:
1. H = High Signal Level
   L = Low Signal Level
   X = Don't Care or Irrelevant
   Z = High Impedance

Product Pin Configuration



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply Voltage Range, V_{DD} ..... –0.5V to 4.6V
Input Voltage Range, V_I ..... -0.5V to 4.6V
Output Voltage Range, V_O (3-Stated) ..... -0.5V to 4.6V
Output Voltage Range, V_O[1] (Active) ..... –0.5V to V_{DD} + 0.5V
DC Input Diode Current (I_{IK}) V_I < 0V ..... -50mA
DC Output Diode Current (I_{OK})
V_O < 0V ..... -50mA
V_O > V_{DD} ..... -50mA
DC Output Source/Sink Current (I_{OH}/I_{OL}) ..... ±50mA
DC V_{DD} or GND Current per Supply Pin (I_{CC} or GND) .... ±100mA
Storage Temperature Range, T_{STG} ..... –65°C to150°C

Note:
Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions[2]

Parameters	Description	Conditions	Min.	Max.	Units
V_{DD}	Supply voltage	Operating	1.8	3.6	V
		Data Retention Only	1.2	3.6	
V_{IH}	High-level input voltage	V_{DD} = 2.7V to 3.6V	2.0		
V_{IL}	Low-level input voltage	V_{DD} = 2.7V to 3.6V		0.8	
V_I	Input voltage		-0.3	3.6	
V_O	Output voltage	Active State	0	V_{DD}	
		Off State	0	3.6	
	Output current in I_{OH}/I_{OL}	V_{DD} = 3.0V to 3.6V V_{DD} = 2.3V to 2.7V V_{DD} = 1.8V		±24 ±18 ±6	mA
$\Delta t/\Delta v$	Input transistion rise or fall rate[3]		0	10	ns/V
T_A	Operating free-air temperature		–40	85	C

Notes:
1. Absolute maximum of I_O must be observed.
2. Unused control inputs must be held HIGH or LOW to prevent them from floating.
3. As measured between 0.8V and 2.0V, V_{DD} = 3.0V.

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted)

DC Characteristics ($2.7V < V_{DD} \leq 3.6V$)

Parameters	Description	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IH}	HIGH Level Input Voltage		2.7 - 3.6	2.0			V
V_{IL}	LOW Level Input Voltage					0.8	
V_{OH}	HIGH Level Output Voltage	I_{OH} = –100 µA		V_{DD} -0.2			
		I_{OH} = –12 mA	2.7	2.2			
		I_{OH} = –18 mA	3.0	2.4			
		I_{OH} = –24 mA		2.2			
V_{OL}	LOW Level Output Voltage	I_{OL} = 100 µA	2.7 - 3.6			0.2	
		I_{OL} = 12 mA	2.7			0.4	
		I_{OL} = 18 mA	3.0			0.4	
		I_{OL} = 24 mA				0.5	
I_I	Input Leakage Current	V_I = 0.0V, V_I = 3.6V	3.6			±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.7 - 3.6			±10	
I_{OFF}	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0			10	
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ to GND	2.7 - 3.6			20	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				±20	
ΔI_{DD}	Increase in I_{DD} per input	$V_{IH} = V_{DD}$ -0.6V, Other inputs at V_{DD} or GND				750	

DC Characteristics ($2.3V \le V_{DD} \le 2.7V$)

Parameters	Description	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IH}	HIGH Level Input Voltage		2.3 - 2.7	1.6			V
V_{IL}	LOW Level Input Voltage					0.7	
V_{OH}	HIGH Level Output Voltage	I_{OH} = -100µA		V_{DD} -0.2			
		I_{OH} = -6mA	2.3	2.0			
		I_{OH} = -12mA		1.8			
		I_{OH} = -18mA		1.7			
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA	2.3 - 2.7			0.2	
		I_{OL} = 12mA	2.3			0.4	
		I_{OL} = 18mA				0.4	
I_I	Input Leakage Current	V_I = 0.0V, V_I = 2.7V	2.7			±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}	2.3 - 2.7			±10	
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0			10	
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	2.3 - 2.7			20	
		$V_{DD} \le (V_I, V_O) \le 3.6V$				±20	

DC Characteristics ($1.8V \le V_{DD} \le 2.3V$)

Parameters	Description	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IH}	HIGH Level Input Voltage		1.8 - 2.3	0.7 x V_{DD}			V
V_{IL}	LOW Level Input Voltage					0.2 x V_{DD}	
V_{OH}	HIGH Level Output Voltage	I_{OH} = -100µA	1.8	V_{DD} -0.2			
		I_{OH} = -6mA		1.4			
V_{OL}	LOW Level Output Voltage	I_{OL} = 100µA				0.2	
		I_{OL} = 6mA				0.3	
I_I	Input Leakage Current	V_I = 0.0V, V_I = 1.8V				±5.0	µA
I_{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$ $V_I = V_{IH}$ or V_{IL}				±10	
I_{OFF}	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$	0			10	
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	1.8			20	
		$V_{DD} \le (V_I, V_O) \le 3.6V$	1.8			±20	

Note:

1. Not guaranteed

AC Electrical Characteristics

Symbol	Parameters	T_A = -40°C to +85°C, C_L = 30pF, R_L = 500Ω						Units
		V_{DD} = 3.3V ± 0.3V		V_{DD} = 2.5V ± 0.2V		V_{DD} = 1.8V		
		Min.	Max.	Min.	Max.	Min.	Max.	
t_{PLH}, t_{PHL}	Prop Delay, DTOQ	0.8	3.0	1.0	3.4	1.5	6.0	ns
t_{PLH}, t_{PHL}	Prop Delay, LE to Q	0.8	3.0	1.0	3.9	1.5	6.0	
t_{PZH}, t_{PZL}	Output Enable Time	0.8	3.5	1.0	4.6	1.5	7.0	
t_{PHZ}, t_{PLZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	5.0	
t_{OSHL}, t_{OSLH}	Output to Output Skew(2)		0.5		0.5		0.5	

Notes:
1. For C_L = 50pF add approximatly 300ps to AC maximum specification.
2. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH or LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

AC Setup Requirements

Symbol	Parameters	T_A= -40ºC to +85ºC, C_L= 30pF, R_L= 500Ω						Units
		V_{DD} =3.3V ± 0.3V		V_{DD} =2.5V ± 0.2V		V_{DD} =1.8V		
		Min.	Typ.	Min.	Typ.	Min.	Typ.	
t_{SU}	Setup Time, D to LE	1.5		1.5		2.5		ns
t_H	Hold Time, D to LE	1.0		1.0		1.0		
t_W	LE Pulse Width, High	1.5		1.5		3.0		

Dynamic Switching Characteristics

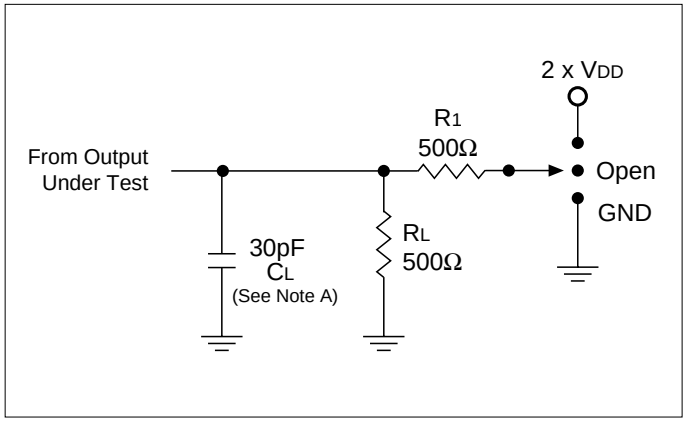
Symbol	Parameters	Conditions	V_{DD}	T_A = +25°C Typical	Units
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	C_L = 50pF, V_{IH} = V_{DD}, V_{IL} = 0V	1.8 2.5 3.3	0.25 0.6 0.8	V
V_{OLP}	Quiet Output Dynamic Valley V_{OL}	C_L = 50pF, V_{IH} = V_{DD}, V_{IL} = 0V	1.8 2.5 3.3	-0.25 -0.6 -0.8	
V_{OLP}	Quiet Output Dynamic Valley V_{OH}	C_L = 50pF, V_{IH} = V_{DD}, V_{IL} = 0V	1.8 2.5 3.3	1.5 1.9 2.2	

Capacitance

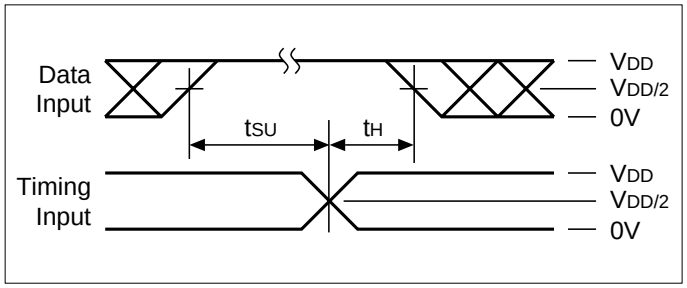
Symbol	Parameters	Conditions	T_A = +25°C Typical	Units
C_{IN}	Input Capacitance	V_{DD} = 1.8, 2.5V or 3.3V, V_I = 0V or V_{DD}	6	pF
C_{OUT}	Output Capacitance	V_I = 0V or V_{DD}, V_{DD} = 1.8V, 2.5V or 3.3V	7	
C_{PD}	Power Dissipation Capacitance	V_I = 0V or V_{DD}, F = 10 MHz V_{DD} = 1.8V, 2.5V or 3.3V	20	

Test Circuits and Switching Waveforms

Parameter Measurement Information (V_{DD} = 1.8V - 3.6V)



Setup, Hold, and Release Timing



Notes:

A. C_L includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is LOW except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the output control.

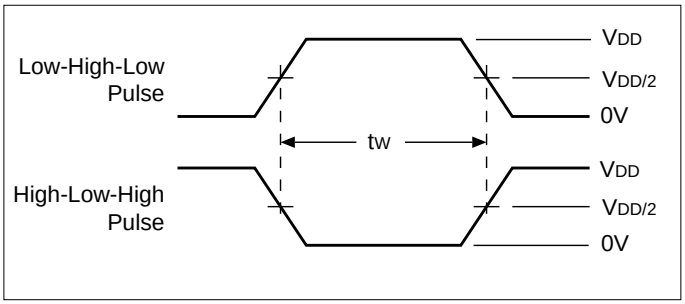
C. All input pulses are supplied by generators having the follow ing characteristics:
$P_{RR} \leq$ 10 MHz, Z_O = 50Ω,
$t_R \leq$ 2ns,
$t_F \leq$ 2ns,
measured from 10% to 90%, unless otherwise specified.

D. The outputs are measured one at a time with one transition per measurement.

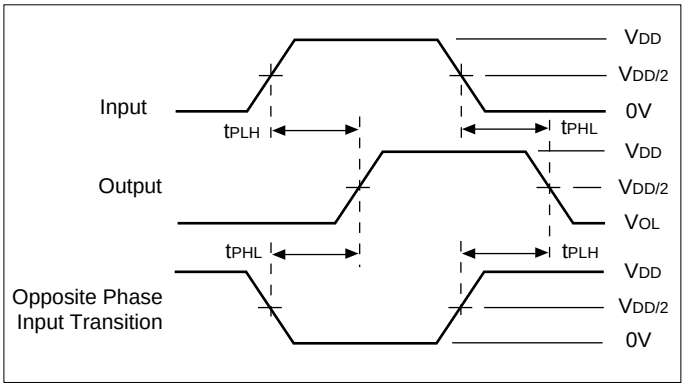
Switch Position

Test	S1
t_{PD}	Open
t_{PLZ}/t_{PZL}	2 x V_{DD}
t_{PHZ}/t_{PZH}	GND

Pulse Width



Propagaton Delay



Enable Disable Timing